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Vishay Semiconductor/Diodes Division VS-100BGQ015HF4

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-100BGQ015HF4 - DIODE SCHOTTKY 15V 100A POWERTAB

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VS-100BGQ015HF4

Vishay Semiconductors

High Performance Schottky Rectifier, 100 A



PowerTab[®]

PRODUCT SUMMARY			
Package	PowerTab [®]		
I _{F(AV)}	100 A		
V _R	15 V		
V _F at I _F	0.45 V		
I _{RM}	870 mA at 100 °C		
T _J max.	125 °C		
Diode variation	Single die		
E _{AS}	9 mJ		

FEATURES

- Ultralow forward voltage drop
- Optimized for OR-ing applications
- Guard ring for enhanced ruggedness and long term reliability
- Screw mounting only
- AEC-Q101 qualified
- 125 °C max. operating junction temperature (V_R < 5 V)
- High frequency operation
- Continuous high current operation
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ015HF4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
	Rectangular waveform	100	А		
I _{F(AV)}	T _C	88	°C		
V _{RRM}		15	V		
I _{FSM}	t _p = 5 μs sine	5000	А		
V _F	100 A _{pk} (typical)	0.39	V		
VF	TJ	125	°C		
TJ	Range	-55 to +125	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-100BGQ015HF4	UNITS
Maximum DC reverse voltage V _R	V	T _J = 100 °C	15	N/
	T _J = 125 °C	5	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 88 °C,	rectangular waveform	100	А
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	5000	А
	10 ms sine or 6 ms rect. pulse		1000		
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 2 \ A, \ L = 4.5 \ mH$ 9 n		mJ	
Repetitive avalanche current	I _{AR}	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		А	

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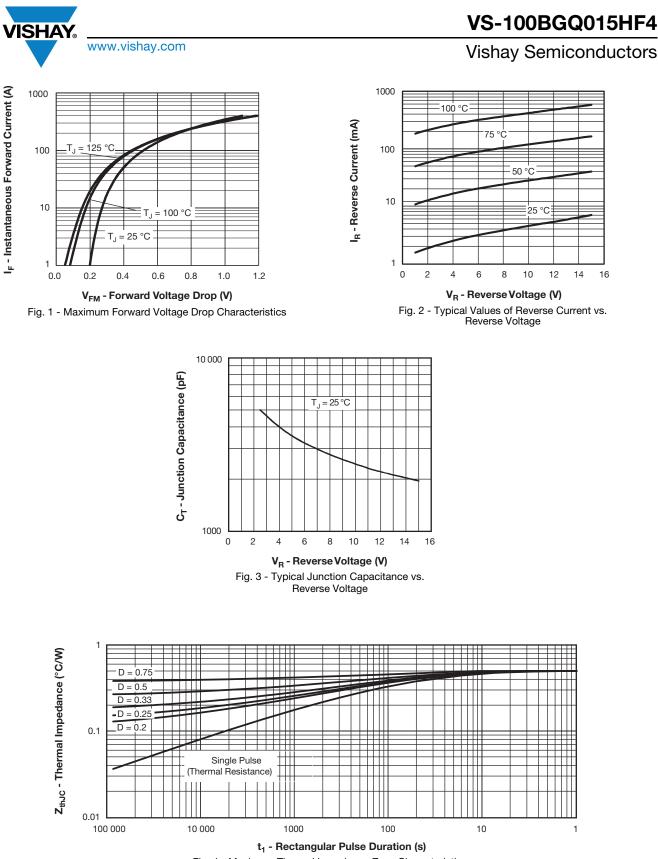
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		MAX.	UNITS
	V _{FM} ⁽¹⁾	50 A	T _J = 25 °C	0.36	0.4	- V
Forward voltage drep		100 A		0.45	0.52	
Forward voltage drop		50 A	- T _J = 125 °C	0.27	0.31	
		100 A		0.39	0.45	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 100 \ ^{\circ}C, V_R = 12 \ V$		480	700	mA
		$T_{J} = 125 \text{ °C}, V_{R} = 5 \text{ V}$		1	1.2	A
		T _J = 25 °C	V _R = Rated V _R	7	18	m 4
		T _J = 100 °C		580	870	mA
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		38	00	pF
Typical series inductance	Ls	Measured from tab to mounting plane 3		.5	nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µs		V/µs		

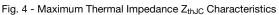
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-55 to +125	°C	
Maximum storage temperature range	T _{Stg}		-55 to +150	C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.50	°C/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.30	·C/W	
Approvimente vueight			5	g	
Approximate weight			0.18	oz.	
Mounting torgue minimum			1.2 (10)	N · m	
Mounting torque maximum			2.4 (20)	(lbf · in)	
Marking device		Case style PowerTab [®]	100BG	Q015H	







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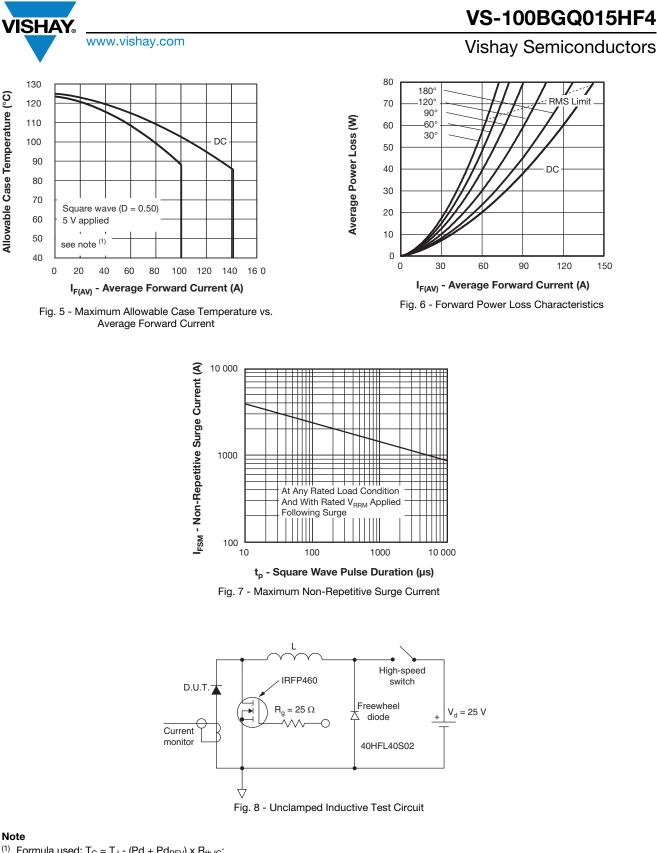
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Allowable Case Temperature (°C)

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ 6); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = 5 \ \mathsf{V} \end{array}$

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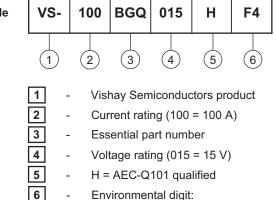
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VS-100BGQ015HF4

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ORDERING INFORMATION TABLE

Device code



- Environmental digit:
 - F4 = RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-100BGQ015HF4	25	375	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95240	
Part marking information	www.vishay.com/doc?95467	
SPICE model	www.vishay.com/doc?95428	
Application note	www.vishay.com/doc?95179	

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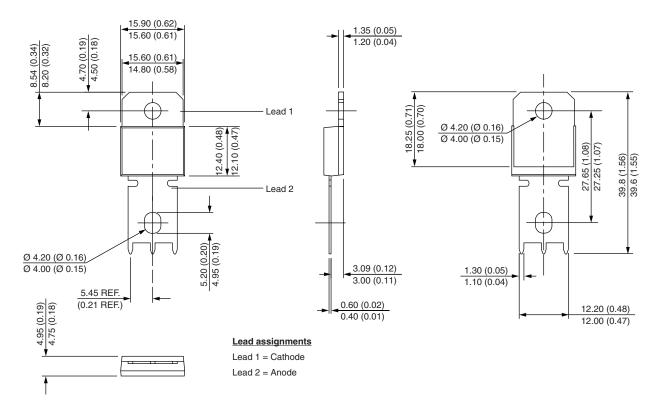


Outline Dimensions

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PowerTab[®]

DIMENSIONS in millimeters (inches)



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